# NSN 5962-01-180-4301

Memory Microcircuit - Page 1 of 1



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## Body Length:

Between 0.755 inches and 0.785 inches

## Body Width:

Between 0.265 inches and 0.291 inches

## **Body Height:**

0.199 inches

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## Features Provided:

Hermetically sealed and programmable and schottky and high speed and 3-state output

## Inclosure Material:

Ceramic

## Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

Transistor-transistor logic

## Input Circuit Pattern:

10 input

**Terminal Surface Treatment:** 

Solder

#### Voltage Rating And Type Per Characteristic:

5.5 volts power source

### Time Rating Per Chacteristic:

60.00 nanoseconds propagation delay time, low to high level output and 60.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Rom

## Memory Capacity:

Unknown

## Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## Terminal Type And Quantity:

16 printed circuit

## Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

#### Fiig:

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